

Area of use

Cu-etch-150 is an alkaline etchant for Cu and is used for the wet-chemical removal of Cu layers with selectivity to metals like Ni, Au, Cr, Sn, Ti. Common areas of use for semiconductor fabrication or microsystem technology.

Advantages and Requirement Profile

Cu-etch-150 offers selectivity to numerous materials. Cu-etch-150 is available in different purity grades. Though alkaline, the etching solution is compatible with resist and can be used at room temperature.

Cu-etch-150 fits to the following requirement profile:

- Selectivity to many materials, e.g. common metals used in electroplating industry
- Available in different purity grades
- Compatible to resist masking
- Usage at room temperature

Inteded Use

- Usable for manual process, tank or etching equipment
- Use in laboratory or production environment only
- Use for commercial application only

Selectivity

Cu-etch-150 is compatible/etches selective to following materials:

- Resists: common Novolak as masking resist (e.g. AZ[®] Photoresist)
- Metals: no attack on Cr, Au, Pt, Sn, Ni, Ti, Ta; TiW, Ag, Zn is attacked
- Semiconductor materials: Si, SiO2, Si3N4

(further information an request)

Etching rate / capacity

Under normal condition, the etching rate is around 100 to 150nm/min (at RT). The etching solution can be operated continuously when pH is stabilized by frequent addition of ammonia (ammonia is evaporating over time, depending on the circulation conditions). Without replenishing the etching solution is depleted earlier. The capacity is about 5g/l to 10g/l Cu. It is recommended to dispose the solution at the latest, when the etching rate has changed by 20% or the etching time increase is not meeting the requirements.



Order number / Article number/ Shipping form

Cu-etch-150 is shipped is shipped ready-to-use. As a standard, all compounds used are level "pure". By standard, the product is 5µm filtered.

Order number: Article number + Container-Code

	Article number	Container-Code				
		11		51	101	201
Cu-etch-150	102150-40	D		F	G	Н

On request: - Certificate of Analysis with individual requirements regarding elements - etching solution in other purity grade or special grade regarding specific elements

<u>Mixture</u>

The product is shipped ready-for-use.

Etching conditions

Temperature:	RT (21°C), maximum 35°C (risk of decomposition)	
pH	stabilisation recommended with ammonia at pH 9.5 to 10.0	
Tank:	Tank for batch process, Petri dish for manual application	
Agitation:	medium;	
0	Circulation; stirring bar; autom./ man. agitation of work piece	
Etching rate:	100 to 150nm per minute (at RTC)	
Pretreatment:	where applicable descum / oxygen plasma for improving the wetting properties of resist or metal mask (no wetting agents needed)	

Etching result / inspection

The completed removal of the Cu can be identified by visual observation. There should be no visible residue of Cu, which should be verified by inspections with optical microscope.

General application notes

Pretreatment

Substrates should be pretreated in oxygen plasma, in order to remove any potential organic residues and to improve the wetting properties of the solution on resist masks. The surface is getting hydrophilic and no extra wetting agents are required.



Etching process

During the etching process, sufficient agitation of the solution or of the substrate is needed. If used in manual processing, the etching time required can be identified by observing a color changeover in the open etching areas and. After visual qualification the etching should be continued for 10% bis 15% of the time elapsed, in order to assure the removal of any residues.

Post treatment

Thorough cleaning with DI-water / quick dump Rinsing dryer or manually drying with nitrogen nozzle

Know issues / trouble shooting

Inhomogeneous etching result / incompleted etching

- Poor wetting / no descum or plasma executed
- Etching solution /etching capacity is consumed
- Not enough agitation

Poor resolution / high undercut

- Poor adhesion of resist
- Excessive etching time

Safety and disposal notes

The mixture contains sodium chlorite and is classified as dangerous according to Regulation (EC) No. 1272/2008.

Refer to the safety and handling recommendations of the material safety datasheet before use.

The etching solution must not be heated over 40°C due to risk of decomposition.

Do not empty into drains or the aquatic environment. Vapour of ammonia can form flammable mixtures with ambient air. Collect used or unused solution in containers and perform waste disposal according to official state regulations.

Technical Support

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